

TECHNICAL DATA
DATA SHEET 2034, REV. A

POWER SCHOTTKY RECTIFIER Very Low Voltage Drop

DESCRIPTION: A 45 VOLT, 15 AMP, POWER SCHOTTKY RECTIFIER IN A HERMETIC SHD-2/2B PACKAGE.

MAXIMUM RATINGS

ALL RATINGS ARE @ $T_C = 25^\circ\text{C}$ UNLESS OTHERWISE SPECIFIED.

| RATING | SYMBOL | MAX. | UNITS |
|--|-----------------|-----------------|--------------------|
| PEAK INVERSE VOLTAGE | PIV | 45 | Volts |
| MAXIMUM DC OUTPUT CURRENT (With Cathode Maintained @ $T_C=100^\circ\text{C}$) | I_o | 15 | Amps |
| MAXIMUM NONREPETITIVE FORWARD SURGE CURRENT ($t=8.3\text{ms}$, Sine) | I_{FSM} | 280 | Amps |
| MAXIMUM JUNCTION CAPACITANCE ($V_r=5\text{V}$) | C_T | 800 | pF |
| MAXIMUM THERMAL RESISTANCE (Junction to Mounting Surface, Cathode) | $R_{\theta JC}$ | 0.85 | $^\circ\text{C/W}$ |
| MAXIMUM OPERATING AND STORAGE TEMPERATURE RANGE | Top/Tstg | -65 to + 150 | $^\circ\text{C}$ |

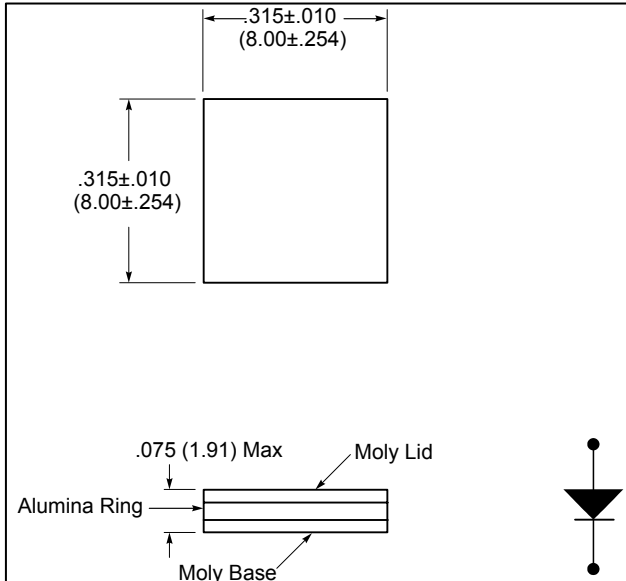
ELECTRICAL CHARACTERISTICS

| CHARACTERISTIC | SYMBOL | MAX. | UNITS |
|--|--------|--------------|-------|
| MAXIMUM FORWARD VOLTAGE DROP, Pulsed ($I_f = 15$ Amps) $T_J = 25^\circ\text{C}$ $T_J = 125^\circ\text{C}$ | V_f | 0.56 0.51 | Volts |
| MAXIMUM REVERSE CURRENT ($I_r @ 45\text{V}$) $T_J = 25^\circ\text{C}$ $T_J = 125^\circ\text{C}$ | I_r | 1.5 70 | mA |

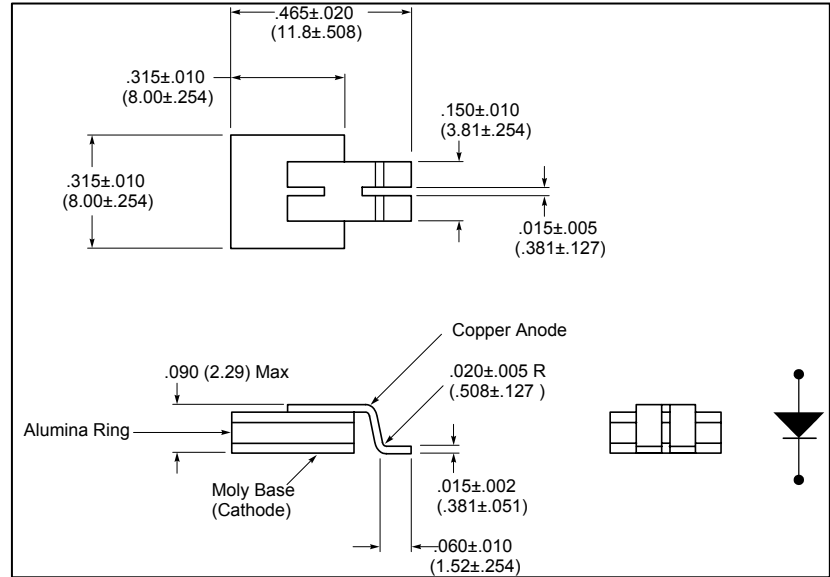
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DATA SHEET 2034, REV. A

MECHANICAL DIMENSIONS: In Inches / mm



SHD-2



SHD-2B

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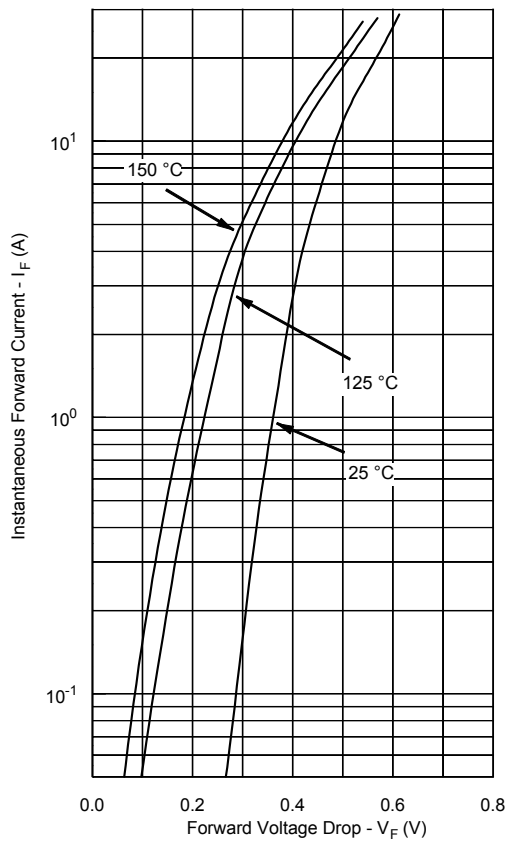
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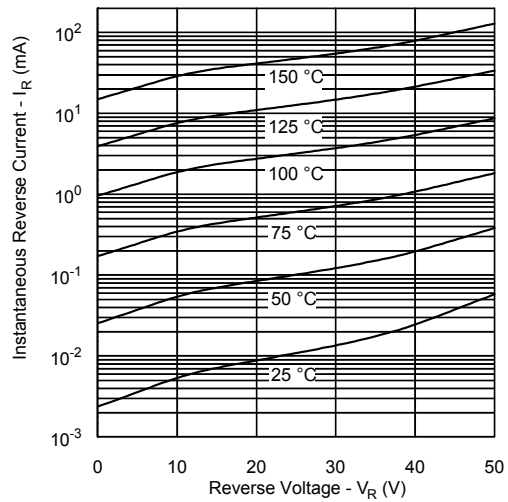
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Note: V_F Curves are shown for die only.

Typical Forward Characteristics



Typical Reverse Characteristics



Typical Junction Capacitance

